

NCE Automotive N-Channel Super Trench Power MOSFET

Description

The NCEAP6090AGU uses **Super Trench** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of $R_{DS(ON)}$ and Q_g . This device is ideal for high-frequency switching and synchronous rectification.

Application

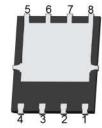
- Automotive application
- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

General Features

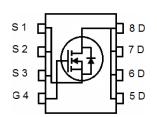
- V_{DS} =60V,I_D =130A
 - $R_{DS(ON)}$ =2.8m Ω (typical) @ V_{GS} =10V $R_{DS(ON)}$ =3.5m Ω (typical) @ V_{GS} =4.5V
- Excellent gate charge x R_{DS(on)} product(FOM)
- Very low on-resistance R_{DS(on)}
- 175 °C operating temperature
- 100% UIS tested
- 100% ΔVds tested
- Pb-free lead plating
- AEC-Q101 qualified

DFN 5X6





Bottom View



Schematic Diagram

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
AP6090AGU	NCEAP6090AGU	DFN5X6-8L	_	-	-

Absolute Maximum Ratings (T_C=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	60	V
Gate-Source Voltage	V _G s	±20	V
Drain Current-Continuous (Silicon Limited) (Note1)	I _D	130	Α
Drain Current-Continuous(T _C =100℃)	I _D (100°C)	90	А
Pulsed Drain Current	I _{DM}	520	А
Maximum Power Dissipation	P _D	120	W
Derating factor		0.8	W/℃
Single pulse avalanche energy (Note 1)	E _{AS}	500	mJ
Operating Junction and Storage Temperature Range	T_{J}, T_{STG}	-55 To 175	$^{\circ}$ C

Thermal Characteristic

Thermal Resistance, Junction-to-Case	Rejc	1.25	°C/W
--------------------------------------	------	------	------

http://www.ncepower.com

NCEAP6090AGU

Electrical Characteristics (Tc=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA	60	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =60V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	Igss	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics						
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	1.0	1.7	2.2	V
rain-Source On-State Resistance	В	V _{GS} =10V, I _D =20A	-	2.8	3.5	mΩ
	R _{DS(ON)}	V _{GS} =4.5V, I _D =20A	-	3.5	4.5	mΩ
Forward Transconductance	g FS	V _{DS} =10V,I _D =20A	40	-	-	S
Dynamic Characteristics			•			
Input Capacitance	C _{lss}	\\ 00\\\\ 0\\	-	4000	-	pF
Output Capacitance	Coss	V_{DS} =30V, V_{GS} =0V, F=1.0MHz	-	680	-	pF
Reverse Transfer Capacitance	Crss	F-1.UIVITIZ	-	23	-	pF
Switching Characteristics (Note 2)						
Turn-on Delay Time	t _{d(on)}		-	11	-	nS
Turn-on Rise Time	t _r	V_{DD} =30 V , I_D =20 A	-	5	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10 V , R_{G} =4.7 Ω	-	56	-	nS
Turn-Off Fall Time	t _f		-	12	-	nS
Total Gate Charge	Qg	\/ 20\/ L 00A	-	67	-	nC
Gate-Source Charge	Q _{gs}	$V_{DS}=30V,I_{D}=20A,$	-	12	-	nC
Gate-Drain Charge	Q _{gd}	V _{GS} =10V	-	8.5	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage	V _{SD}	V _{GS} =0V,I _S =20A	-	-	1.2	V
Diode Forward Current	Is		-	-	130	Α
Reverse Recovery Time	t _{rr}	$T_J = 25^{\circ}C, I_F = I_S$	-	48	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs	-	60	-	nC

Notes:

- 1. Defined by design. Not subject to production test
- 2. EAS condition : Tj=25 $^{\circ}\text{C}$,V_DD=20V,V_G=10V,L=0.5mH,Rg=25 Ω
- 3. Guaranteed by design, not subject to production
- 4. These curves are based on the junction-to-case thermal impedance which is measured with the device mounted to a large heatsink, assuming a maximum junction temperature of T_{J(MAX)}=175 °C. The SOA curve provides a single pulse rating.





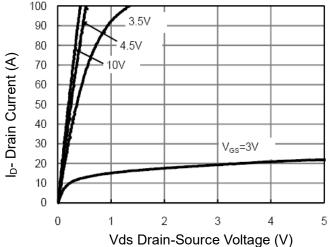


Figure 1 Output Characteristics

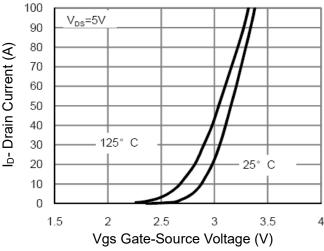


Figure 2 Transfer Characteristics

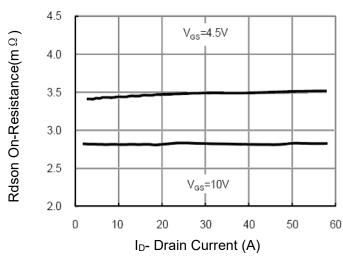


Figure 3 Rdson- Drain Current

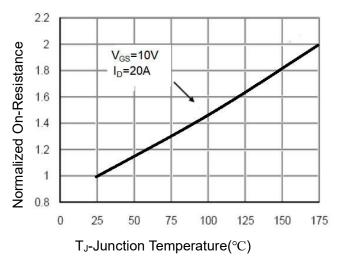


Figure 4 Rdson-JunctionTemperature

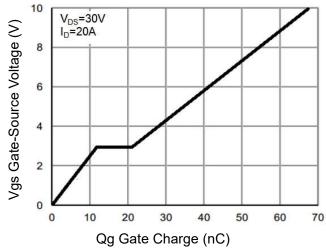


Figure 5 Gate Charge

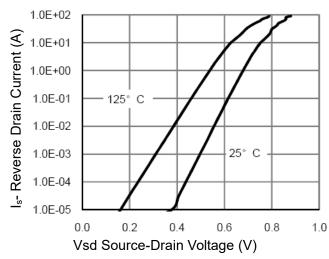
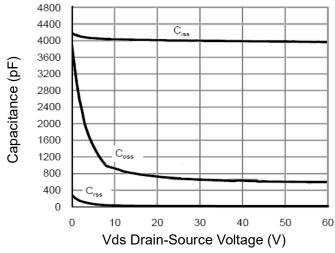


Figure 6 Source- Drain Diode Forward





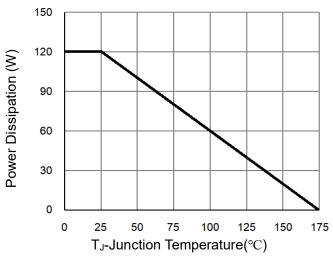
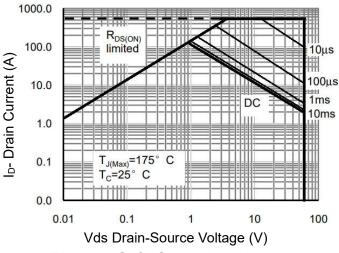


Figure 7 Capacitance vs Vds

Figure 9 Power De-rating



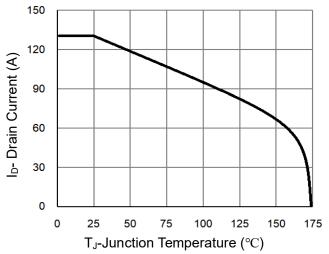
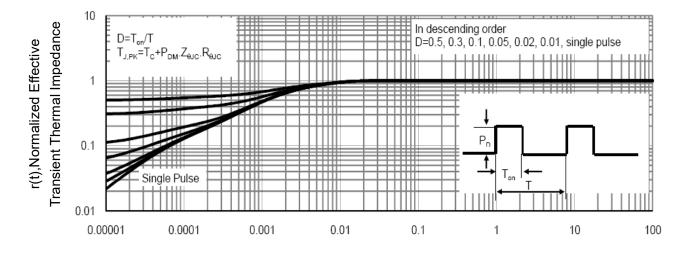


Figure 8 Safe Operation Area (Note3)

Figure 10 Current De-rating

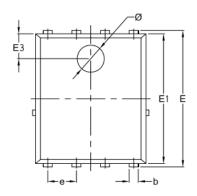


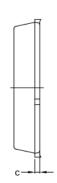
Square Wave Pluse Duration(sec)

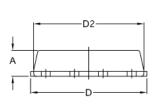
Figure 11 Normalized Maximum Transient Thermal Impedance

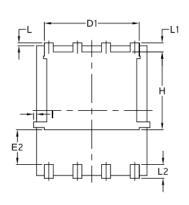


DFN5X6-8L Package Information









S Y	COMMON					
M B	N	IM	INCH			
O L	MIN.	MAX.	MIN.	MAX.		
Α	1.03	1.17	0.0406	0.0461		
b	0.34	0.48	0.0134	0.0189		
С	0.15	0.30	0.0059	0.0118		
D	4.80	5.40	0.1890	0.2126		
D1	4.11	4.31	0.1618	0.1697		
D2	4.80	5.00	0.1890	0.1969		
Е	5.95	6.15	0.2343	0.2421		
E1	5.65	5.85	0.2224	0.2303		
E2	1.40	_	0.0551	_		
E3	1.00	1.20	0.0394	0.0472		
е	1.27 BSC		0.05 BSC			
L	0.05	0.25	0.0020	0.0098		
L1	0.38	0.50	0.0150	0.0197		
L2	0.38	0.71	0.0150	0.0280		
Н	3.30	3.50	0.1299	0.1378		
I	_	0.18	_	0.0070		
Ø	1.10	1.30	0 0.0433 0.05			

http://www.ncepower.com

NCEAP6090AGU

Attention:

- Any and all NCE power products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your NCE power representative nearest you before using any NCE power products described or contained herein in such applications.
- NCE power assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all NCE power products described or contained herein.
- Specifications of any and all NCE power products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.
- NCE power CO.,LTD. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with some probability. It is possible that these probabilistic failures could give rise to accidents or events that could endanger human lives, that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all NCE power products(including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of NCE power CO.,LTD.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production. NCE power believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the NCE power product that you intend to use.
- This catalog provides information as of Aug.2022. Specifications and information herein are subject to change without notice.